74AUP1T45

Low-power dual supply translating transceiver; 3-state Rev. 01 — 18 October 2006 Product da

Product data sheet

General description

The 74AUP1T45 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The 74AUP1T45 is a single bit transceiver featuring two data input-outputs (A and B), a direction control input (DIR) and dual supply pins (V_{CC(A)} and V_{CC(B)}) which enable bidirectional level translation. Both $V_{CC(A)}$ and $V_{CC(B)}$ can be supplied at any voltage between 1.1 V and 3.6 V making the device suitable for interfacing between any of the low voltage nodes (1.2 V, 1.5 V, 1.8 V, 2.5 V and 3.3 V). Pins A and DIR are referenced to $V_{CC(A)}$ and pin B is referenced to $V_{CC(B)}$. A HIGH on DIR allows transmission from A to B and a LOW on DIR allows transmission from B to A.

Schmitt trigger action on all inputs makes the circuit tolerant of slower input rise and fall times across the entire $V_{CC(A)}$ and $V_{CC(B)}$ ranges. The device ensures low static and dynamic power consumption and is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing any damaging backflow current through the device when it is powered down. In suspend mode when either V_{CC(A)} or V_{CC(B)} are at GND, both A and B are in the high-impedance OFF-state.

2. **Features**

- Wide supply voltage range:
 - ◆ V_{CC(A)}: 1.1 V to 3.6 V
 - ♦ V_{CC(B)}: 1.1 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114-D Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101-C exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Suspend mode
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation



Low-power dual supply translating transceiver; 3-state

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- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

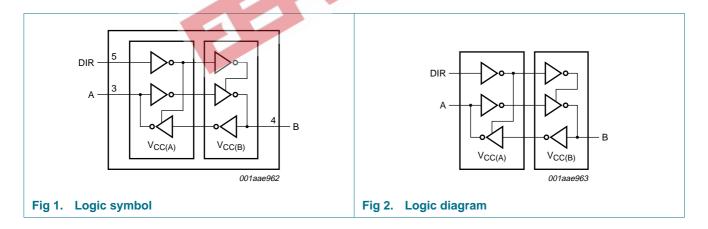
Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1T45GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74AUP1T45GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886				
74AUP1T45GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891				

4. Marking

Table 2. Marking

3	- 15 /14
Type number	Marking code
74AUP1T45GW	a5
74AUP1T45GM	a 5
74AUP1T45GF	a5

5. Functional diagram

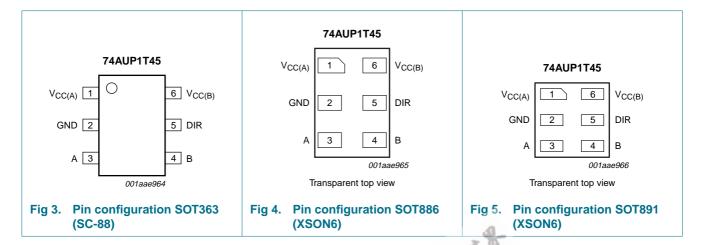


74AUP1T45 **NXP Semiconductors**

Low-power dual supply translating transceiver; 3-state

Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

_	(SC-88)	(XSON6)	(XSON6)
	6.2 Pin desc	cription	The state of the s
Table 3.	Pin description	36 25 1	M.C
Symbol	Pin	Description	
$V_{CC(A)}$	1	supply voltage port A	
GND	2	ground (0 V)	
Α	3	data input or output A	
В	4	data input or output B	
DIR	5	direction control DIR	
V _{CC(B)}	6	supply voltage port B	

Functional description

Function table[1] Table 4.

Supply voltage	Input ^[2]	Input/output[3]	Input/output[3]			
V _{CC(A)} , V _{CC(B)}	DIR	A	В			
1.1 V to 3.6 V	L	A = B	input			
1.1 V to 3.6 V	Н	input	B = A			
GND	Χ	suspend mode	suspend mode			

- [1] H = HIGH voltage level;
 - L = LOW voltage level;
 - X = don't care.
- [2] The DIR input circuit is referenced to $V_{CC(A)}$.
- [3] The input circuit of the data I/Os are always active.

Low-power dual supply translating transceiver; 3-state

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

			•		,
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage port A		-0.5	+4.6	V
V _{CC(B)}	supply voltage port B		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-	-50	mA
VI	input voltage		[<u>1</u>] -0.5	+4.6	V
lok	output clamping current	V _O < 0 V	-	-50	mA
Vo	output voltage	Active mode			
Vo		A port	[1][2] -0.5	$V_{CC(A)} + 0.5$	V
		B port	<u>[1][2]</u> –0.5	$V_{CC(B)} + 0.5$	V
		suspend or 3-state mode	<u>[1][2]</u> –0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		- %-	50	mA
I _{GND}	ground current		4000	-50	mA
T _{stg}	storage temperature	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	<u>[3]</u> -	250	mW
			A		

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage port A		1.1	3.6	V
$V_{CC(B)}$	supply voltage port B		1.1	3.6	V
V_{I}	input voltage		0	3.6	V
V _O	output voltage		<u>[1]</u> 0	V_{CCO}	V
T_{amb}	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CCI} = 1.1 \text{ V to } 3.6 \text{ V}$	0	200	ns/V

^[1] V_{CCO} is the supply voltage associated with the output port.

^[2] The values of V_{CC(A)} and V_{CC(B)} are provided in the recommended operating conditions; see Table 6.

^[3] For SC-88 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 packages: above 45 °C the value of P_{tot} derates linearly with 2.4 mW/K.

Low-power dual supply translating transceiver; 3-state

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{amb} = 25$	5 °C					
V_{IH}	HIGH-level input	data input [1][3				
	voltage	V _{CCI} = 1.1 V to 1.95 V	$0.65 \times V_{CCI}$	-	-	V
		V_{CCI} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CCI} = 3.0 V to 3.6 V	2.0	-	-	V
		DIR input [1][4				
		V _{CCI} = 1.1 V to 1.95 V	$0.65 \times V_{CC(A)}$	-	-	V
		V _{CCI} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CCI} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	data input [1][3				
	voltage	V _{CCI} = 1.1 V to 1.95 V	- 4	-	$0.35 \times V_{CCI}$	V
		V _{CCI} = 2.3 V to 2.7 V	15-111	-	0.7	V
		$V_{CCI} = 1.1 \text{ V to } 1.95 \text{ V}$ $V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CCI} = 3.0 \text{ V to } 3.6 \text{ V}$ DIR input $V_{CCI} = 1.1 \text{ V to } 1.95 \text{ V}$ $V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$	- CIT	-	0.9	V
		DIR input	0.			
		V _{CCI} = 1.1 V to 1.95 V		-	$0.35 \times V_{CC(A)}$	V
		V _{CCI} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CCI} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$				
		$I_{O} = -20 \mu A;$ $V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	V _{CCO} – 0.1	-	-	V
			$0.75 \times V_{CCO}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.65 \text{ V}$	1.32	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IL}$				
	voltage	$I_O = 20 \mu A$; $V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		$I_O = 1.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V}$	-	-	$0.3 \times V_{CCO}$	V
		$I_O = 1.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.4 \text{ V}$	-	-	0.31	V
		$I_O = 1.9 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.65 \text{ V}$	-	-	0.31	V
		$I_{O} = 2.3 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	-	-	0.31	V
		$I_O = 3.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	-	-	0.44	V
		$I_O = 2.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	-	-	0.31	V
		$I_O = 4.0 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	-	-	0.44	V
l _l	input leakage current	DIR input; $V_I = GND$ to $V_{CC(A)}$; $V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μΑ

Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
l _{OZ}	OFF-state output current	A or B port; $V_I = V_{IH}$ or V_{IL} ; $V_O = 0$ V to V $V_{CC(A)} = V_{CC(B)} = 1.1$ V to 3.6 V	cco; [2]	-	-	±0.1	μΑ
l _{OFF}	power-off leakage current	A port; V_1 or V_O = 0 V to 3.6 V; $V_{CC(A)}$ = 0 V; $V_{CC(B)}$ = 1.1 V to 3.6 V		-	-	±0.2	μΑ
		B port; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(B)} = 0$ V; $V_{CC(A)} = 1.1$ V to 3.6 V		-	-	±0.2	μΑ
		DIR input; V_I or $V_O = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 1.1$ V to 3.6 V		-	-	±0.2	μΑ
ΔI_{OFF}	additional power-off	A port; V_1 or V_O = 0 V to 3.6 V; $V_{CC(A)}$ = 0 V to 0.2 V; $V_{CC(B)}$ = 1.1 V to 3.	6 V	-	-	±0.2	μΑ
	leakage current	B port; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(B)} = 0$ V to 0.2 V; $V_{CC(A)} = 1.1$ V to 3.	6 V	-	-	±0.2	μΑ
		DIR input; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V to 0.2 V; $V_{CC(B)} = 1.1$ V to 3.	6 V	-	-	±0.2	μΑ
I _{CC}	supply current	A port; $V_I = GND$ or V_{CCI} ; $I_O = 0$ A	[1]	.cn			
		$V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	- 40	16- /**	-	0.5	μΑ
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$	几個	- C/1	-	0.5	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 3.6 \text{ V}$	3		0	-	μΑ
		B port; $V_I = GND$ or V_{CCI} ; $I_O = 0$ A	<u>[1]</u>				
		$V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$		-	-	0.5	μΑ
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$		-	0	-	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 3.6 \text{ V}$		-	-	0.5	μΑ
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); $I_O = 0$ A; $V_I = GND$ or V_{CCI} ; $V_{CC(A)} = V_{CC(B)} = 1.1$ V to 3.6 V	<u>[1]</u>	-	-	0.5	μΑ
ΔI_{CC}	additional supply current	A port; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$; A port at $V_{CC(A)} - 0.6 \text{ V}$; DIR at $V_{CC(A)}$; B port = open		-	-	40	μΑ
		B port; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$; B port at $V_{CC(B)} - 0.6 \text{ V}$; DIR at GND; A port = open		-	-	40	μΑ
		DIR input; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$; A port at $V_{CC(A)}$ or GND; B port = open; DIR at $V_{CC(A)} - 0.6 \text{ V}$		-	-	40	μА
Cı	input capacitance	DIR input; $V_I = GND$ or $V_{CC(A)}$; $V_{CC(A)} = V_{CC(B)} = 1.1$ V to 3.6 V		-	0.9	-	pF
C _{I/O}	input/output capacitance	A and B port; suspend mode; $V_{CCI} = 0 \text{ V}_{CCO}$ $V_{CCO} = 1.1 \text{ V to } 3.6 \text{ V}; V_O = V_{CCO} \text{ or GNI}$		-	2.0	-	pF

Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +85 °C					
V _{IH}	HIGH-level input	data input [1][3				
	voltage	V _{CCI} = 1.1 V to 1.95 V	$0.65 \times V_{\text{CCI}}$	-	-	V
		V _{CCI} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CCI} = 3.0 V to 3.6 V	2.0	-	-	V
		DIR input [1][4				
		V _{CCI} = 1.1 V to 1.95 V	$0.65 \times V_{CC(A)}$	-	-	V
		V _{CCI} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CCI} = 3.0 V to 3.6 V	2.0	-	-	V
V_{IL}	LOW-level input	data input [1][3				
	voltage	V _{CCI} = 1.1 V to 1.95 V	-	-	$0.35 \times V_{CCI}$	V
		V _{CCI} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CCI} = 3.0 V to 3.6 V	- 4	-	0.9	V
		DIR input [1][4	14 10			
		$V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CCI} = 3.0 \text{ V to } 3.6 \text{ V}$ DIR input $V_{CCI} = 1.1 \text{ V to } 1.95 \text{ V}$ $V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CCI} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{I} = V_{IH}$	- Ch	-	$0.35 \times V_{CC(A)}$	V
		V _{CCI} = 2.3 V to 2.7 V	A.	-	0.7	V
		V _{CCI} = 3.0 V to 3.6 V		-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$				
		$I_O = -20 \mu A;$ $V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	V _{CCO} – 0.1	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V}$	$0.7 \times V_{CCO}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	2.55	-	-	V
V_{OL}	LOW-level output	$V_I = V_{IL}$				
	voltage	I_{O} = 20 μ A; $V_{CC(A)}$ = $V_{CC(B)}$ = 1.1 V to 3.6 V	-	-	0.1	V
		$I_O = 1.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V}$	-	-	$0.3 \times V_{\text{CCO}}$	V
		$I_O = 1.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.4 \text{ V}$	-	-	0.37	V
		$I_{O} = 1.9 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.65 \text{ V}$	-	-	0.35	V
		$I_O = 2.3 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	-	-	0.33	V
		$I_{O} = 3.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	-	-	0.45	V
		$I_{O} = 2.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	-	-	0.33	V
		$I_{O} = 4.0 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	-	-	0.45	V
I _I	input leakage current	DIR input; $V_I = GND$ to $V_{CC(A)}$; $V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μΑ
I _{OZ}	OFF-state output current		-	-	±0.5	μΑ

Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
l _{OFF}	power-off leakage current	A port; V_1 or $V_O = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 1.1$ V to 3.6 V	-	-	±0.5	μΑ
		B port; V_1 or V_O = 0 V to 3.6 V; $V_{CC(B)}$ = 0 V; $V_{CC(A)}$ = 1.1 V to 3.6 V	-	-	±0.5	μΑ
		DIR input; V_I or $V_O = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 1.1$ V to 3.6 V	-	-	±0.5	μΑ
ΔI_{OFF}	additional power-off	A port; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V to 0.2 V; $V_{CC(B)} = 1.1$ V to 3.6 V	- /	-	±0.6	μΑ
	leakage current	B port; V_1 or V_0 = 0 V to 3.6 V; $V_{CC(B)}$ = 0 V to 0.2 V; $V_{CC(A)}$ = 1.1 V to 3.6 V	- /	-	±0.6	μΑ
		DIR input; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V to 0.2 V; $V_{CC(B)} = 1.1$ V to 3.6 V	- /	-	±0.6	μΑ
I _{CC}	supply current	A port; $V_I = GND$ or V_{CCI} ; $I_O = 0$ A	<u>[1]</u>			
		$V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μΑ
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$	11		0.9	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 3.6 \text{ V}$	2 34	0	-	μΑ
		B port; $V_I = GND$ or V_{CCI} ; $I_O = 0$ A	<u>[1]</u>			
		$V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	"W.	-	0.9	μΑ
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$	0.0	0	-	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 3.6 \text{ V}$	-	-	0.9	μΑ
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); $I_O = 0$ A; $V_I = GND$ or V_{CCI} ; $V_{CC(A)} = V_{CC(B)} = 1.1$ V to 3.6 V	<u>[1]</u> -	-	0.9	μΑ
Δl _{CC}	additional supply current	A port; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$; A port at $V_{CC(A)} - 0.6 \text{ V}$; DIR at $V_{CC(A)}$; B port = open	-	-	50	μΑ
		B port; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$; B port at $V_{CC(B)} - 0.6 \text{ V}$; DIR at GND; A port = open	-	-	50	μΑ
		DIR input; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$; A port at $V_{CC(A)}$ or GND; B port = open; DIR at $V_{CC(A)} - 0.6 \text{ V}$	-	-	50	μΑ
T _{amb} = -	40 °C to +125 °C					
V_{IH}	HIGH-level input	data input	[1][3]			
	voltage	V _{CCI} = 1.1 V to 1.95 V	0.7	× V _{CCI} -	-	V
		V_{CCI} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CCI} = 3.0 \text{ V to } 3.6 \text{ V}$	2.0	-	-	V
		DIR input	[1][4]			
		V _{CCI} = 1.1 V to 1.95 V	0.7	× V _{CC(A)} -	-	V
		$V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6	-	-	V
		V _{CCI} = 3.0 V to 3.6 V	2.0	-	-	V

Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{IL}	LOW-level input	data input [1][3				
	voltage	V _{CCI} = 1.1 V to 1.95 V	-	-	$0.3 \times V_{CCI}$	V
		V _{CCI} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CCI} = 3.0 V to 3.6 V	-	-	0.9	V
		DIR input [1][4				
		V _{CCI} = 1.1 V to 1.95 V	-	-	$0.3 \times V_{\text{CC(A)}}$	V
		V_{CCI} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CCI} = 3.0 \text{ V to } 3.6 \text{ V}$	-	-	0.9	V
V_{OH}	HIGH-level	$V_I = V_{IH}$				
	output voltage	$I_O = -20 \mu A;$ $V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	V _{CCO} – 0.11	-	-	V
		$I_O = -1.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V}$	$0.6 \times V_{CCO}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.4 \text{ V}$	0.93	-	-	V
		$I_O = -1.9 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.65 \text{ V}$	1.17	-	-	V
		$I_O = -1.9$ mA, $V_{CC(A)} = V_{CC(B)} = 1.65$ V $I_O = -2.3$ mA; $V_{CC(A)} = V_{CC(B)} = 2.3$ V	1.77	-	-	V
		$I_O = -3.1 \text{ mA}$; $V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	1.67	-	-	V
		$I_O = -2.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	2.30	-	-	V
V_{OL}	LOW-level output	$V_I = V_{IL}$				
	voltage	$I_O = 20 \mu A$; $V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	0.11	V
		$I_O = 1.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V}$	-	-	$0.33 \times V_{CCO}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.4 \text{ V}$	-	-	0.41	V
		$I_{O} = 1.9 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 1.65 \text{ V}$	-	-	0.39	V
		$I_O = 2.3 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	-	-	0.36	V
		$I_O = 3.1 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 2.3 \text{ V}$	-	-	0.50	V
		$I_O = 2.7 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	-	-	0.36	V
		$I_O = 4.0 \text{ mA}; V_{CC(A)} = V_{CC(B)} = 3.0 \text{ V}$	-	-	0.50	V
l _i	input leakage current	DIR input; $V_I = GND$ to $V_{CC(A)}$; $V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μΑ
l _{OZ}	OFF-state output current	A or B port; $V_I = V_{IH}$ or V_{IL} ; $V_O = 0$ V to V_{CCO} ; $V_{CC(A)} = V_{CC(B)} = 1.1$ V to 3.6 V	-	-	±0.75	μΑ
l _{OFF}	power-off leakage current	A port; V_I or $V_O = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 1.1$ V to 3.6 V	-	-	±0.75	μΑ
		B port; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(B)} = 0$ V; $V_{CC(A)} = 1.1$ V to 3.6 V	-	-	±0.75	μΑ
		DIR input; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 1.1$ V to 3.6 V	-	-	±0.75	μΑ

Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ΔI_{OFF}	additional power-off	A port; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V to 0.2 V; $V_{CC(B)} = 1.1$ V to 3.6 V	-	-	±0.75	μΑ
	leakage current	B port; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(B)} = 0$ V to 0.2 V; $V_{CC(A)} = 1.1$ V to 3.6 V	-	-	±0.75	μΑ
		DIR input; V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC(A)} = 0$ V to 0.2 V; $V_{CC(B)} = 1.1$ V to 3.6 V	-	-	±0.75	μΑ
I_{CC}	supply current	A port; $V_I = GND$ or V_{CCI} ; $I_O = 0$ A	<u>[1]</u>			
		$V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$	-	-	1.4	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 3.6 \text{ V}$	-	0	-	μΑ
		B port; $V_I = GND$ or V_{CCI} ; $I_O = 0$ A	[1]			
		$V_{CC(A)} = V_{CC(B)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$	-	0	-	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 3.6 \text{ V}$	- 8-	-	1.4	μΑ
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); $I_O = 0$ A; $V_I = GND$ or V_{CCI} ; $V_{CC(A)} = V_{CC(B)} = 1.1$ V to 3.6 V	a cn	-	1.4	μΑ
Δl _{CC}	additional supply current	A port; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$; A port at $V_{CC(A)} - 0.6 \text{ V}$; DIR at $V_{CC(A)}$; B port = open	m.cn	-	75	μΑ
		B port; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$; B port at $V_{CC(B)} = 0.6 \text{ V}$; DIR at GND; A port = open	-	-	75	μΑ
		DIR input; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$; A port at $V_{CC(A)}$ or GND; B port = open; DIR at $V_{CC(A)} - 0.6 \text{ V}$	-	-	75	μΑ

^[1] V_{CCI} is the supply voltage associated with the data input port.

^[2] V_{CCO} is the supply voltage associated with the output port.

^[3] For V_{CCI} values not specified in the data sheet: minimum $V_{IH} = 0.7 \times V_{CCI}$ and maximum $V_{IL} = 0.3 \times V_{CCI}$.

^[4] For V_{CCI} values not specified in the data sheet: minimum $V_{IH} = 0.7 \times V_{CC(A)}$ and maximum $V_{IL} = 0.3 \times V_{CC(A)}$.

^[5] All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation.

Low-power dual supply translating transceiver; 3-state

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +′	125 °C	Unit
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 pl	F; V _{CC(A)} = 1.1 V to	1.3 V						'		
t _{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.8	15.4	28.0	2.4	28.3	31.2	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.8	10.2	16.2	2.6	17.5	19.3	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.4	8.1	13.0	2.2	14.4	15.9	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	6.3	10.0	2.1	10.7	11.8	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.3	5.6	9.0	1.9	9.7	10.7	ns
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.7	5.3	8.5	2.5	8.7	9.6	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.9	5.3	8.4	2.7	8.7	9.7	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.7	5.3	8.5	2.5	9.0	10.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$	2	2.7	5.3	8.7	2.5	8.9	9.9	ns
		V _{CC(B)} = 3.0 V to 3.6 V	13	2.9	5.3	8.7	2.5	9.1	10.1	ns
		DIR to B; see Figure 7	[3]	C						
		V _{CC(B)} = 1.1 V to 1.3 V		6.1	13.2	22.1	5.4	23.4	25.8	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		5.0	9.3	13.9	4.4	15.2	16.7	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		4.2	8.1	12.3	3.6	13.5	14.9	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.3	6.3	9.3	2.9	10.2	11.2	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.6	6.3	9.2	3.2	9.7	10.7	ns
$C_L = 5 pl$	F; $V_{CC(A)} = 1.4 \text{ V to}$	1.6 V								
t_{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.5	14.5	26.6	2.2	27.1	29.9	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.5	9.4	14.5	2.3	15.9	17.5	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.1	7.4	11.2	1.9	12.7	14.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.2	5.5	8.0	1.8	8.9	9.8	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.0	4.7	6.8	1.6	7.6	8.4	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +′	125 °C	Unit
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{dis}	disable time	DIR to A; see Figure 7	[3]					1		
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.0	3.8	5.3	1.9	5.7	6.3	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.2	3.8	5.3	2.0	5.7	6.4	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.1	3.8	5.5	1.8	5.9	6.6	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.1	3.8	5.5	1.9	5.9	6.6	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.2	3.8	5.5	1.9	6.0	6.6	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		5.7	12.7	21.0	5.2	22.3	24.6	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.7	8.7	12.7	4.1	14.1	15.5	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.9	7.4	10.9	3.3	12.3	13.5	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.0	5.6	7.8	2.6	8.8	9.7	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.3	5.5	7.4	2.9	8.1	8.9	ns
$C_L = 5 pl$	F; $V_{CC(A)} = 1.65 \text{ V to}$	1.95 V			在如		0			
t_{pd}	propagation delay	A to B or B to A; see Figure 6	<u>[2]</u>	23	1	1.0				
		V _{CC(B)} = 1.1 V to 1.3 V	13	2.4	14.2	26.1	2.0	26.5	29.2	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.4	9.1	13.9	2.1	15.4	17.0	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.0	7.0	10.7	1.7	12.1	13.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.0	5.1	7.4	1.6	8.2	9.1	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		1.9	4.3	6.1	1.5	6.9	7.7	ns
t_{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.0	3.5	4.8	1.8	5.2	5.8	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.1	3.5	4.8	1.9	5.2	5.7	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.0	3.5	5.0	1.8	5.4	6.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.0	3.5	4.9	1.8	5.4	6.0	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.1	3.5	4.9	1.8	5.4	6.0	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		5.8	12.4	20.6	5.1	21.9	24.2	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.6	8.4	12.2	3.9	13.5	14.9	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.8	7.1	10.4	3.2	11.8	13.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.9	5.2	7.3	2.5	8.3	9.1	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.1	5.1	6.9	2.7	7.5	8.3	ns
$C_L = 5 pl$	F; $V_{CC(A)} = 2.3 \text{ V to}$	2.7 V								
t_{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.4	13.6	25.5	2.0	25.9	28.6	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.3	8.5	13.3	2.1	14.7	16.2	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		1.9	6.5	10.0	1.7	11.4	12.5	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		1.9	4.6	6.7	1.6	7.5	8.3	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		1.8	3.8	5.3	1.4	6.2	6.8	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions		·	25 °C		-4	0 °C to +′	125 °C	Unit
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{dis}	disable time	DIR to A; see Figure 7	[3]					(()	
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		1.4	2.5	3.3	1.3	3.6	4.0	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		1.6	2.5	3.3	1.4	3.6	4.0	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		1.5	2.5	3.4	1.3	3.8	4.2	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		1.4	2.5	3.4	1.3	3.8	4.2	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		1.6	2.5	3.4	1.3	3.7	4.1	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		5.8	12.3	20.4	5.1	21.8	24.0	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.5	8.3	11.9	4.0	13.2	14.5	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.7	7.0	10.0	3.2	11.3	12.5	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.8	5.0	6.8	2.5	7.8	8.6	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.1	4.9	6.4	2.7	7.0	7.8	ns
C _L = 5 pl	F; V _{CC(A)} = 3.0 V to	3.6 V			在都		0			
t _{pd}	propagation delay	A to B or B to A; see Figure 6	<u>[2]</u>	2	1	1.0	-			
		V _{CC(B)} = 1.1 V to 1.3 V	13	2.3	13.1	24.9	2.0	25.2	27.8	ns
		V _{CC(B)} = 1.4 V to 1.6 V		2.3	8.1	12.8	2.0	14.1	15.5	ns
		V _{CC(B)} = 1.65 V to 1.95 V		1.9	6.1	9.5	1.7	10.8	12.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		1.9	4.3	6.2	1.6	7.0	7.7	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		1.7	3.5	5.0	1.4	5.7	6.3	ns
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		1.7	2.8	3.5	1.5	3.8	4.2	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		1.8	2.8	3.5	1.7	3.8	4.2	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		1.7	2.8	3.6	1.5	4.0	4.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		1.7	2.8	3.6	1.5	3.9	4.4	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		1.8	2.8	3.6	1.5	3.9	4.3	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		5.8	12.3	20.6	5.1	22.0	24.2	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.6	8.3	11.8	4.0	13.1	14.5	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.8	6.9	10.0	3.2	11.3	12.5	ns
		$V_{CC(B)}$ = 2.3 V to 2.7 V		2.8	5.0	6.7	2.5	7.6	8.4	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.1	4.9	6.3	2.7	6.9	7.6	ns
C _L = 10 p	$pF; V_{CC(A)} = 1.1 V to$	o 1.3 V								
t_{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.0	16.2	29.8	2.7	30.2	33.3	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		3.0	10.8	17.5	2.7	18.6	20.5	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.1	8.7	13.5	2.8	14.6	16.1	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.7	6.8	10.5	2.4	11.2	12.4	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.7	6.1	9.6	2.4	10.1	11.1	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +	125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Max	
								(85 °C)	(125 °C)	
t_{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.2	6.5	9.9	3.1	10.2	11.3	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		3.5	6.5	10.0	3.2	10.2	11.3	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.7	6.5	9.8	3.5	10.1	11.1	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.2	6.5	10.1	3.1	10.2	11.3	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.6	6.5	10.1	3.2	10.3	11.4	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		6.4	14.3	23.5	5.8	24.8	27.4	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		5.3	10.2	15.4	4.6	16.6	18.4	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		5.2	9.2	13.6	4.7	14.7	16.2	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.6	7.1	10.1	3.2	11.0	12.1	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		4.4	7.6	10.8	3.8	11.4	12.5	ns
C _L = 10	oF; V _{CC(A)} = 1.4 V to	o 1.6 V			在		0			
t _{pd}	propagation delay	A to B or B to A; see Figure 6		2 1	100	1.0				
		V _{CC(B)} = 1.1 V to 1.3 V	13	2.7	15.3	28.3	2.4	29.0	31.9	ns
		V _{CC(B)} = 1.4 V to 1.6 V		2.7	10.0	15.8	2.5	17.0	18.7	ns
		V _{CC(B)} = 1.65 V to 1.95 V		2.8	7.9	11.8	2.5	13.0	14.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.4	6.0	8.6	2.2	9.4	10.4	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.4	5.2	7.4	2.1	8.0	8.9	ns
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.5	4.7	6.4	2.3	6.8	7.6	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.7	4.7	6.5	2.4	6.9	7.6	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.9	4.7	6.5	2.6	6.9	7.6	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	4.7	6.5	2.3	6.9	7.6	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.8	4.7	6.6	2.4	6.9	7.7	ns
		DIR to B; see Figure 7	<u>[3]</u>							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		6.1	13.7	22.4	5.6	23.8	26.3	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		5.0	9.6	14.2	4.3	15.5	17.1	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		4.9	8.5	12.3	4.4	13.4	14.8	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.3	6.4	8.7	3.0	9.6	10.6	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		4.1	6.7	9.1	3.5	9.7	10.8	ns
C _L = 10	pF; V _{CC(A)} = 1.65 V	to 1.95 V								
t _{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.6	15.0	27.8	2.3	28.3	31.2	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.6	9.7	15.2	2.3	16.5	18.2	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.7	7.5	11.2	2.3	12.4	13.7	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.3	5.6	7.9	2.0	8.8	9.7	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.3	4.8	6.7	1.9	7.4	8.2	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +1	125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Max	
								(85 °C)	(125 °C)	
t_{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.5	4.6	6.2	2.4	6.6	7.3	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.7	4.6	6.3	2.5	6.7	7.4	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.9	4.6	6.3	2.7	6.7	7.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	4.6	6.2	2.4	6.7	7.4	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.8	4.6	6.3	2.5	6.7	7.4	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		6.1	13.5	22.1	5.4	23.4	25.8	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		5.0	9.3	13.6	4.2	14.9	16.5	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		4.8	8.3	11.8	4.2	13.0	14.3	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.2	6.0	8.1	2.8	9.1	10.0	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.9	6.4	8.5	3.3	9.2	10.2	ns
C _L = 10 p	oF; $V_{CC(A)} = 2.3 \text{ V to}$	2.7 V			李都		0			
t _{pd}	propagation delay	A to B or B to A; see Figure 6	<u>[2]</u>	2	1	1.0	-			
		V _{CC(B)} = 1.1 V to 1.3 V	13	2.5	14.4	27.2	2.3	27.8	30.6	ns
		V _{CC(B)} = 1.4 V to 1.6 V		2.5	9.1	14.6	2.3	15.8	17.4	ns
		V _{CC(B)} = 1.65 V to 1.95 V		2.6	7.0	10.5	2.2	11.7	12.9	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.2	5.1	7.2	1.9	8.0	8.9	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.2	4.3	5.9	1.9	6.6	7.3	ns
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		1.8	3.3	4.2	1.7	4.6	5.1	ns
		V _{CC(B)} = 1.4 V to 1.6 V		2.0	3.3	4.4	1.8	4.7	5.2	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.1	3.3	4.4	2.0	4.7	5.2	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		1.8	3.3	4.3	1.7	4.7	5.2	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.1	3.3	4.4	1.8	4.7	5.2	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		6.1	13.4	21.8	5.4	23.2	25.6	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.9	9.2	13.3	4.2	14.6	16.1	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		4.8	8.1	11.4	4.2	12.5	13.8	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.1	5.8	7.7	2.8	8.6	9.5	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.9	6.2	8.0	3.3	8.7	9.6	ns
C _L = 10 p	oF; $V_{CC(A)} = 3.0 \text{ V to}$	3.6 V								
t _{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.5	14.0	26.6	2.2	27.0	29.8	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.5	8.7	14.0	2.3	15.1	16.7	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.5	6.6	10.1	2.2	11.2	12.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.2	4.8	6.8	1.9	7.5	8.3	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.1	4.0	5.5	1.9	6.1	6.8	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +′	125 °C	Unit
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	_
t _{dis}	disable time	DIR to A; see Figure 7	[3]					(00 0)	(120 0)	
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.3	4.0	5.0	2.2	5.3	5.9	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.5	4.0	5.2	2.3	5.4	6.0	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.6	4.0	5.2	2.5	5.4	6.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.3	4.0	5.1	2.2	5.4	6.0	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.6	4.0	5.2	2.3	5.4	6.0	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		6.2	13.5	22.0	5.5	23.4	25.8	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.9	9.2	13.2	4.2	14.6	16.1	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		4.8	8.1	11.3	4.3	12.4	13.7	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.1	5.8	7.6	2.8	8.5	9.4	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.9	6.2	7.9	3.3	8.5	9.5	ns
C _L = 15 p	pF; V _{CC(A)} = 1.1 V to				70.00		0			
t _{pd}	propagation delay	A to B or B to A; see Figure 6	<u>[2]</u>	2 1	12					
		V _{CC(B)} = 1.1 V to 1.3 V	13	3.4	16.9	31.6	3.0	32.0	35.2	ns
		V _{CC(B)} = 1.4 V to 1.6 V		3.7	11.3	18.2	3.1	19.5	21.5	ns
		V _{CC(B)} = 1.65 V to 1.95 V		3.2	9.1	14.3	3.0	15.6	17.2	ns
		V _{CC(B)} = 2.3 V to 2.7 V		3.2	7.3	11.2	2.8	12.0	13.2	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.1	6.5	10.2	2.6	10.7	11.8	ns
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.9	7.6	11.4	3.8	11.7	12.9	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.5	7.6	11.3	4.1	11.7	12.9	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		4.2	7.6	11.3	4.1	11.7	12.9	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.9	7.6	11.7	3.8	11.9	13.1	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		4.5	7.6	11.7	4.1	11.9	13.1	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		7.2	15.4	24.9	6.5	26.3	29.0	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		6.3	11.1	16.3	5.4	17.7	19.5	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		5.7	10.4	15.0	5.2	16.2	17.9	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		4.1	7.9	11.4	3.8	12.1	13.4	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		5.3	8.8	12.2	4.9	12.7	14.1	ns
C _L = 15	$pF; V_{CC(A)} = 1.4 V to$	1.6 V								
t_{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.1	16.1	30.1	2.8	30.7	33.8	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		3.4	10.5	16.5	2.8	17.9	19.7	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.0	8.4	12.6	2.7	13.9	15.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.9	6.4	9.3	2.5	10.1	11.2	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.8	5.6	8.0	2.3	8.7	9.6	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions		·	25 °C		-4	0 °C to +′	125 °C	Unit
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{dis}	disable time	DIR to A; see Figure 7	[3]					(66 6)	(120 0)	
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.1	5.6	7.6	2.9	8.0	8.9	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		3.5	5.6	7.5	3.1	8.0	8.8	ns
		V _{CC(B)} = 1.65 V to 1.95 V		3.3	5.6	7.6	3.1	8.0	8.9	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.1	5.6	7.7	2.9	8.1	9.0	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.5	5.6	7.8	3.1	8.1	9.0	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		6.9	14.9	23.8	6.4	25.3	27.9	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		6.0	10.5	15.1	5.2	16.6	18.3	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		5.4	9.7	13.7	5.0	15.0	16.5	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.8	7.2	9.9	3.5	10.7	11.9	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		5.0	8.0	10.5	4.6	11.1	12.3	ns
C _L = 15 p	oF; V _{CC(A)} = 1.65 V	to 1.95 V			在如		0			
t _{pd}	propagation delay	A to B or B to A; see Figure 6	<u>[2]</u>	2 1	12	1.0				
		V _{CC(B)} = 1.1 V to 1.3 V	13	3.0	15.8	29.6	2.6	30.1	33.2	ns
		V _{CC(B)} = 1.4 V to 1.6 V		3.2	10.2	15.9	2.6	17.4	19.2	ns
		V _{CC(B)} = 1.65 V to 1.95 V		2.8	8.0	12.0	2.5	13.4	14.8	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.8	6.0	8.6	2.3	9.5	10.5	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.6	5.2	7.3	2.2	8.0	8.9	ns
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.2	5.8	7.6	3.1	8.0	8.9	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		3.7	5.8	7.6	3.3	8.1	8.9	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.5	5.8	7.7	3.3	8.1	9.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.2	5.8	7.8	3.1	8.2	9.0	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.7	5.8	7.8	3.4	8.1	9.0	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		6.9	14.7	23.4	6.2	24.9	27.4	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		5.9	10.2	14.6	5.0	16.0	17.7	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		5.3	9.4	13.2	4.8	14.5	16.0	ns
		$V_{CC(B)}$ = 2.3 V to 2.7 V		3.7	6.8	9.4	3.4	10.2	11.3	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		4.9	7.6	9.9	4.4	10.6	11.7	ns
C _L = 15 p	$pF; V_{CC(A)} = 2.3 V to$	2.7 V								
t_{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.0	15.2	29.0	2.6	29.5	32.5	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		3.1	9.6	15.3	2.6	16.7	18.4	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.7	7.5	11.3	2.5	12.6	13.9	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.7	5.5	7.9	2.3	8.7	9.6	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.5	4.7	6.5	2.1	7.2	8.0	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +′	125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Max	
								(85 °C)	(125 °C)	
t_{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		2.4	4.1	5.2	2.2	5.6	6.2	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		2.7	4.1	5.3	2.4	5.7	6.3	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.5	4.1	5.4	2.4	5.7	6.3	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.4	4.1	5.4	2.2	5.7	6.3	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.7	4.1	5.3	2.4	5.6	6.2	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		6.9	14.6	23.2	6.2	24.7	27.2	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		5.9	10.1	14.2	5.0	15.6	17.3	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		5.3	9.2	12.8	4.8	14.0	15.5	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.7	6.7	8.9	3.4	9.8	10.8	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		4.8	7.4	9.4	4.4	10.1	11.2	ns
C _L = 15 p	oF; V _{CC(A)} = 3.0 V to	3.6 V			在都		0			
t _{pd}	propagation delay	A to B or B to A; see Figure 6	<u>[2]</u>	3	100	1.0				
		V _{CC(B)} = 1.1 V to 1.3 V	13	2.9	14.7	28.3	2.6	28.8	31.7	ns
		V _{CC(B)} = 1.4 V to 1.6 V		3.1	9.2	14.7	2.6	16.0	17.7	ns
		V _{CC(B)} = 1.65 V to 1.95 V		2.7	7.1	10.9	2.4	12.1	13.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.7	5.2	7.4	2.2	8.2	9.1	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		2.5	4.5	6.1	2.1	6.8	7.5	ns
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.1	5.3	6.5	3.0	6.9	7.6	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		3.5	5.3	6.6	3.2	7.0	7.7	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.3	5.3	6.7	3.2	7.0	7.8	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.1	5.3	6.8	3.0	7.1	7.8	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.5	5.3	6.6	3.2	6.9	7.6	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		6.9	14.6	23.4	6.3	24.9	27.4	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		5.9	10.1	14.2	5.0	15.6	17.2	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		5.3	9.2	12.7	4.8	13.9	15.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.7	6.6	8.8	3.4	9.6	10.6	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		4.8	7.4	9.3	4.4	10.0	11.0	ns
C _L = 30	oF; V _{CC(A)} = 1.1 V to	1.3 V								
t _{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		4.2	19.1	36.0	3.8	36.8	40.5	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.5	12.8	20.6	4.0	22.0	24.2	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		4.2	10.4	16.2	3.8	17.4	19.2	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		4.0	8.3	12.4	3.5	13.2	14.5	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		4.0	7.5	11.5	3.7	12.5	13.8	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +′	125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Max	
								(85 °C)	(125 °C)	
t_{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		5.6	11.0	15.7	5.5	16.2	17.9	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		6.1	11.0	15.6	6.0	15.9	17.5	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		6.6	11.0	15.5	6.5	15.8	17.4	ns
		$V_{CC(B)}$ = 2.3 V to 2.7 V		5.6	11.0	15.6	5.5	15.8	17.5	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		7.0	11.0	15.9	6.6	16.7	18.4	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		8.7	18.9	29.0	8.1	30.5	33.6	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		7.3	13.8	19.3	6.8	20.7	22.8	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		8.1	13.7	19.2	7.7	20.3	22.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		5.2	10.3	14.0	4.9	14.7	16.2	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		8.1	12.5	16.5	7.5	18.0	19.9	ns
C _L = 30 p	oF; V _{CC(A)} = 1.4 V to	o 1.6 V			在部		0			
t _{pd}	propagation delay	A to B or B to A; see Figure 6	<u>[2]</u>	2 13	100	1.0				
		V _{CC(B)} = 1.1 V to 1.3 V	13	4.0	18.2	34.5	3.5	35.5	39.1	ns
		V _{CC(B)} = 1.4 V to 1.6 V		4.2	12.0	18.9	3.7	20.3	22.4	ns
		V _{CC(B)} = 1.65 V to 1.95 V		3.9	9.6	14.4	3.5	15.8	17.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.8	7.5	10.4	3.2	11.4	12.6	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.7	6.7	9.3	3.4	10.4	11.4	ns
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		4.4	8.3	10.8	4.3	11.4	12.6	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.8	8.3	10.7	4.6	11.2	12.3	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		5.2	8.3	10.8	5.0	11.2	12.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		4.4	8.3	10.8	4.3	11.1	12.3	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		5.5	8.3	11.0	5.1	11.8	13.0	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		8.4	18.3	27.9	7.9	29.5	32.5	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		7.1	13.2	18.2	6.6	19.6	21.6	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		7.8	13.1	17.9	7.4	19.1	21.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		4.9	9.6	12.6	4.6	13.4	14.8	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		7.7	11.7	14.8	7.2	16.3	18.0	ns
$C_L = 30 \; \mu$	oF; V _{CC(A)} = 1.65 V	to 1.95 V								
t _{pd}	propagation delay	A to B or B to A; see Figure 6	[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.9	18.0	34.0	3.4	34.9	38.4	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		4.1	11.7	18.3	3.5	19.8	21.9	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.8	9.2	13.9	3.4	15.2	16.8	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.6	7.1	9.8	3.1	10.8	11.9	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.5	6.3	8.6	3.2	9.7	10.7	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-40	0 °C to +1	125 °C	Uni
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		5.0	9.2	11.7	4.8	12.3	13.6	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		5.4	9.2	11.7	5.3	12.1	13.4	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		5.8	9.1	11.9	5.7	12.3	13.6	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		5.0	9.1	11.7	4.8	12.1	13.4	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		6.2	9.2	11.9	5.8	12.7	14.1	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		8.4	18.1	27.6	7.8	29.1	32.0	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		7.0	12.9	17.7	6.4	19.1	21.0	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		7.7	12.8	17.4	7.2	18.6	20.6	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		4.8	9.3	12.0	4.5	12.9	14.2	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		7.6	11.3	14.2	7.0	15.8	17.4	ns
C _L = 30 p	oF; V _{CC(A)} = 2.3 V to	2.7 V			在部		0			
t _{pd}	propagation delay	A to B or B to A; see Figure 6	<u>[2]</u>	2 6 3	13					
		V _{CC(B)} = 1.1 V to 1.3 V	13	3.8	17.4	33.4	3.4	34.3	37.8	ns
		V _{CC(B)} = 1.4 V to 1.6 V		4.0	11.1	17.7	3.5	19.1	21.1	ns
		V _{CC(B)} = 1.65 V to 1.95 V		3.7	8.7	13.2	3.3	14.4	15.9	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.4	6.5	9.1	3.0	10.0	11.1	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		3.5	5.7	7.8	3.1	8.9	9.8	ns
t _{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.6	6.5	8.1	3.5	8.5	9.4	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		3.9	6.5	8.1	3.8	8.5	9.4	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		4.2	6.5	8.3	4.1	8.6	9.5	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.6	6.5	8.2	3.5	8.5	9.4	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		4.5	6.5	8.2	4.2	8.9	9.8	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		8.4	18.0	27.4	7.8	28.8	31.8	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		7.0	12.8	17.3	6.4	18.7	20.6	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		7.7	12.6	17.0	7.2	18.2	20.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		4.8	9.1	11.6	4.5	12.4	13.7	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		7.6	11.1	13.7	7.0	15.3	16.9	ns
C _L = 30 p	oF; V _{CC(A)} = 3.0 V to	o 3.6 V								
pd	propagation delay		[2]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		3.8	16.9	32.8	3.3	33.5	36.9	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		3.9	10.7	17.1	3.5	18.5	20.4	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		3.7	8.3	12.7	3.3	13.9	15.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		3.2	6.3	8.6	2.9	9.5	10.5	ns

Table 8. Dynamic characteristics ...continued Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-40	0 °C to +1	125 °C	Unit
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t_{dis}	disable time	DIR to A; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		5.0	9.0	11.0	4.9	11.5	12.7	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		5.4	9.0	11.1	5.3	11.4	12.6	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		5.9	9.0	11.3	5.7	11.6	12.8	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		5.0	9.0	11.2	4.9	11.4	12.6	ns
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		6.2	9.0	11.2	5.9	11.9	13.2	ns
		DIR to B; see Figure 7	[3]							
		$V_{CC(B)} = 1.1 \text{ V to } 1.3 \text{ V}$		8.4	18.1	27.6	7.8	29.1	32.0	ns
		$V_{CC(B)} = 1.4 \text{ V to } 1.6 \text{ V}$		7.0	12.8	17.3	6.4	18.6	20.6	ns
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		7.7	12.6	17.0	7.2	18.1	19.9	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		4.8	9.0	11.5	4.5	12.3	13.6	ns
		V _{CC(B)} = 3.0 V to 3.6 V		7.6	9.0	13.6	7.0	15.1	16.7	ns

Low-power dual supply translating transceiver; 3-state

 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +	125 °C	Unit
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
$C_L = 5 p$	F, 10 pF, 15 pF and	30 pF								
C_{PD}	power dissipation	A port; (direction A to B)	[4][5]							
	capacitance	$V_{CC(A)} = V_{CC(B)} = 1.2 \text{ V}$		-	0.6	-	-	-	-	рF
		$V_{CC(A)} = V_{CC(B)} = 1.5 \text{ V}$		-	0.7	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 1.8 \text{ V}$		-	0.7	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 2.5 \text{ V}$		-	0.9	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$		-	1.1	-	-	-	-	pF
		A port; (direction B to A)	[4][5]							
		$V_{CC(A)} = V_{CC(B)} = 1.2 \text{ V}$		-	3.7	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 1.5 \text{ V}$		-	3.8	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 1.8 \text{ V}$		-	4.0	7.0	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 2.5 \text{ V}$		-	4.6	通用	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$		-	5.2	-	0	-	-	pF
		B port; (direction A to B)	[4][5]	c 3						
		$V_{CC(A)} = V_{CC(B)} = 1.2 \text{ V}$	4 0	L.	3.7	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 1.5 \text{ V}$		C	3.8	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 1.8 \text{ V}$		-	4.0	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 2.5 \text{ V}$		-	4.6	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$		-	5.2	-	-	-	-	рF
		B port; (direction B to A)	[4][5]							
		$V_{CC(A)} = V_{CC(B)} = 1.2 \text{ V}$		-	0.6	-	-	-	-	рF
		$V_{CC(A)} = V_{CC(B)} = 1.5 \text{ V}$		-	0.7	-	-	-	-	рF
		$V_{CC(A)} = V_{CC(B)} = 1.8 \text{ V}$		-	0.7	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 2.5 \text{ V}$		-	0.9	-	-	-	-	рF
		$V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$		-	1.1	-	-	-	-	pF

^[1] All typical values are measured at nominal $V_{\text{CC(A)}}$ and $V_{\text{CC(B)}}$.

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}{}^2 \times f_o) \text{ where:}$

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of the outputs.

[5] $f_i = 1 \text{ MHz}$; $V_I = \text{GND to } V_{CC}$

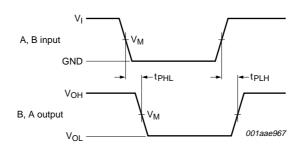
^[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

^[3] t_{dis} is the same as t_{PLZ} and t_{PHZ} .

^[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

Low-power dual supply translating transceiver; 3-state

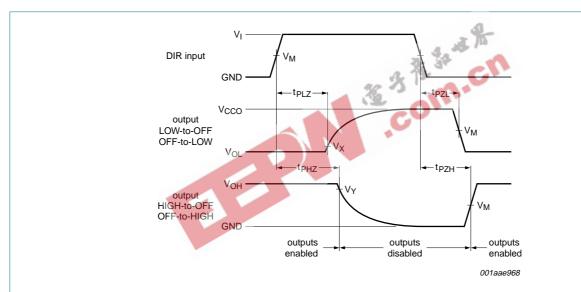
12. Waveforms



Measurement points are given in Table 9.

 V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig 6. The data input (A, B) to output (B, A) propagation delay times



Measurement points are given in Table 9.

 $\ensuremath{V_{OL}}$ and $\ensuremath{V_{OH}}$ are typical output voltage drops that occur with the output load.

Fig 7. Enable and disable times

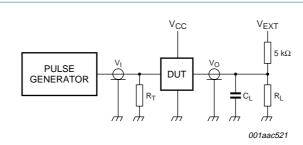
Table 9. Measurement points

Supply voltage	Input ^[1]	Output[2]		
V _{CC(A)} , V _{CC(B)}	V _M	V _M	V _X	V _Y
1.1 V to 1.6 V	$0.5 \times V_{CCI}$	$0.5 \times V_{CCO}$	V _{OL} + 0.1 V	V _{OH} – 0.1 V
1.65 V to 2.7 V	$0.5 \times V_{CCI}$	$0.5 \times V_{CCO}$	V _{OL} + 0.15 V	V _{OH} – 0.15 V
3.0 V to 3.6 V	$0.5 \times V_{CCI}$	$0.5 \times V_{CCO}$	V_{OL} + 0.3 V	V _{OH} – 0.3 V

^[1] V_{CCI} is the supply voltage associated with the data input port.

^[2] V_{CCO} is the supply voltage associated with the output port.

Low-power dual supply translating transceiver; 3-state



Test data is given in Table 10.

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance.

 V_{EXT} = External voltage for measuring switching times.

Fig 8. Load circuitry for switching times

Table 10. Test data

Supply voltage	Input		Load	V _{EXT}	V _{EXT}	
$V_{CC(A)}, V_{CC(B)}$	V _I [1]	$t_r = t_f$	CL	R _L [2] t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ} [3]
1.1 V to 3.6 V	V_{CCI}	≤ 3.0 ns	5 pF, 10 pF, 15 pF and 30 pF	$5 k\Omega$ or $1 M\Omega$ open	GND	$2\times V_{CCO}$

- [1] V_{CCI} is the supply voltage associated with the data input port.
- [2] For measuring enable and disable times R_L = 5 $k\Omega$, for measuring propagation delays, setup and hold times and pulse width R_L = 1 $M\Omega$.
- [3] V_{CCO} is the supply voltage associated with the output port.

Low-power dual supply translating transceiver; 3-state

13. Application information

13.1 Unidirectional logic level-shifting application

The circuit given in <u>Figure 9</u> is an example of the 74AUP1T45 being used in an unidirectional logic level-shifting application.

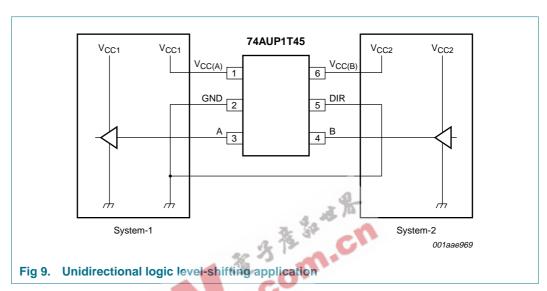


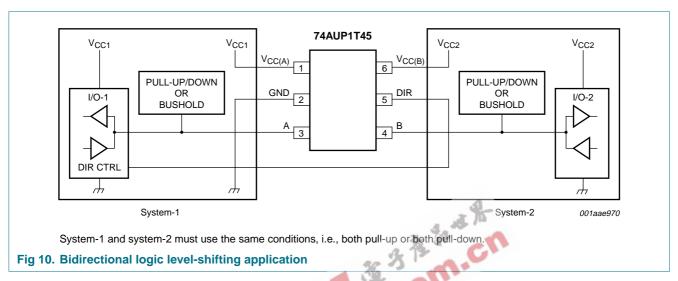
Table 11. Description unidirectional logic level-shifting application

Pin	Name	Function	Description
1	V _{CC(A)}	V _{CC1}	supply voltage of system-1 (1.1 V to 3.6 V)
2	GND	GND	device ground (0 V)
3	Α	OUT	output level depends on V _{CC1} voltage
4	В	IN	input threshold value depends on V _{CC2} voltage
5	DIR	DIR	the GND (LOW level) determines B port to A port direction
6	$V_{CC(B)}$	V_{CC2}	supply voltage of system-2 (1.1 V to 3.6 V)

Low-power dual supply translating transceiver; 3-state

13.2 Bidirectional logic level-shifting application

<u>Figure 10</u> shows the 74AUP1T45 being used in a bidirectional logic level-shifting application. Since the device does not have an output enable (OE) pin, the system designer should take precautions to avoid bus contention between system-1 and system-2 when changing directions.



<u>Table 12</u> gives a sequence that will illustrate data transmission from system-1 to system-2 and then from system-2 to system-1.

Table 12. Description bidirectional logic level-shifting application[1][2]

State	DIR CTRL	I/O-1	1/0-2	Description
1	H	output	input	system-1 data to system-2
2	Н	Z	Z	system-2 is getting ready to send data to system-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on the pull-up or pull-down.
3	L	Z	Z	DIR bit is flipped. I/O-1 and I/O-2 still are disabled. The bus-line state depends on the pull-up or pull-down.
4	L	input	output	system-2 data to system-1

^[1] System-1 and system-2 must use the same conditions, i.e., both pull-up or both pull-down.

L = LOW voltage level;

Z = high-impedance OFF-state.

^[2] H = HIGH voltage level;

Low-power dual supply translating transceiver; 3-state

13.3 Power-up considerations

A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies. Take the following precautions to guard against such power-up problems:

- · Connect ground before any supply voltage is applied.
- Power-up V_{CC(A)}.
- V_{CC(B)} can be ramped up along with or after V_{CC(A)}.

13.4 Enable times

Calculate the enable times for the 74AUP1T45 using the following formulas:

- t_{PZH} (DIR to A) = t_{PLZ} (DIR to B) + t_{PLH} (B to A)
- t_{PZL} (DIR to A) = t_{PHZ} (DIR to B) + t_{PHL} (B to A)
- t_{PZH} (DIR to B) = t_{PLZ} (DIR to A) + t_{PLH} (A to B)
- t_{PZL} (DIR to B) = t_{PHZ} (DIR to A) + t_{PHL} (A to B)

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the 74AUP1T45 initially is transmitting from A to B, then the DIR bit is switched, the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.

Low-power dual supply translating transceiver; 3-state

14. Package outline

Plastic surface-mounted package; 6 leads

SOT363

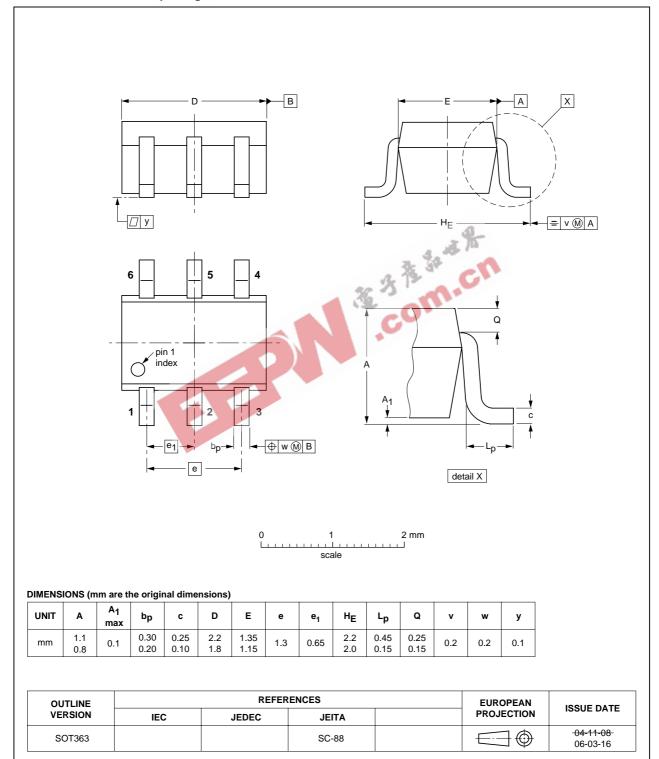


Fig 11. Package outline SOT363 (SC-88)

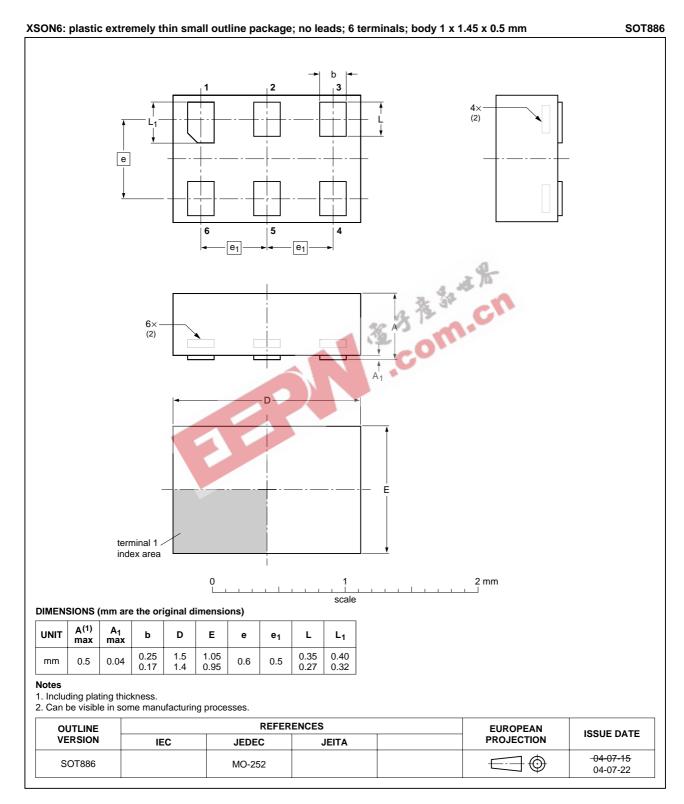


Fig 12. Package outline SOT886 (XSON6)

Low-power dual supply translating transceiver; 3-state

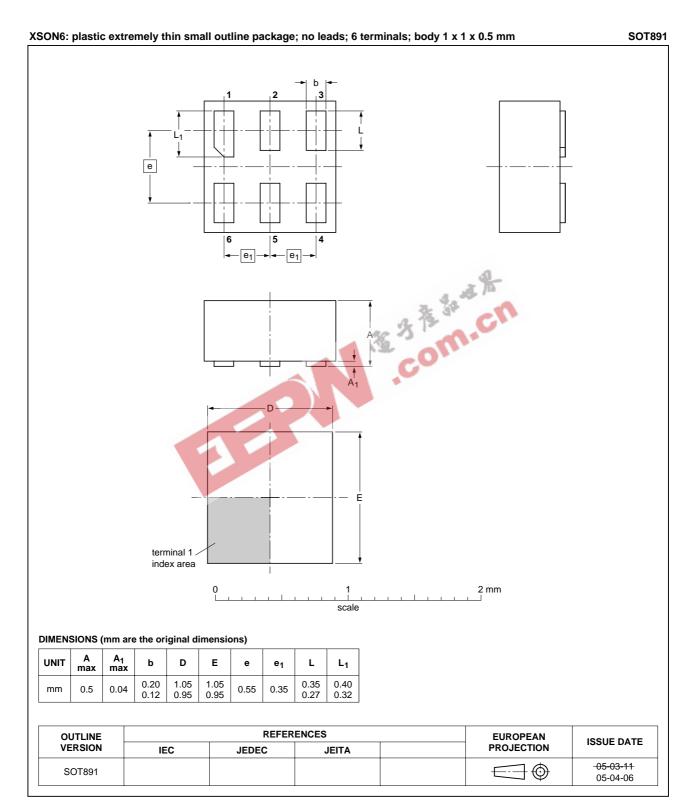


Fig 13. Package outline SOT891 (XSON6)

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Low-power dual supply translating transceiver; 3-state

15. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

16. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1T45_1	20061018	Product data sheet	- 40 45	-
			.com.cl	



Low-power dual supply translating transceiver; 3-state

17. Legal information

17.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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Low-power dual supply translating transceiver; 3-state

19. Contents

1	General description	. 1
2	Features	. 1
3	Ordering information	. 2
4	Marking	. 2
5	Functional diagram	. 2
6	Pinning information	. 3
6.1	Pinning	
6.2	Pin description	
7	Functional description	. 3
8	Limiting values	. 4
9	Recommended operating conditions	
10	Static characteristics	. 5
11	Dynamic characteristics	11
12	Waveforms	23
13	Application information	25
13.1	Unidirectional logic level-shifting application	25
13.1 13.2	Bidirectional logic level-shifting application	26
13.2 13.3	Bidirectional logic level-shifting application Power-up considerations	26 27
13.2	Bidirectional logic level-shifting application Power-up considerations	26 27 27
13.2 13.3	Bidirectional logic level-shifting application Power-up considerations	26 27 27
13.2 13.3 13.4	Bidirectional logic level-shifting application Power-up considerations	26 27 27 28
13.2 13.3 13.4 14	Bidirectional logic level-shifting application Power-up considerations Enable times	26 27 27 28 31
13.2 13.3 13.4 14	Bidirectional logic level-shifting application Power-up considerations Enable times	26 27 27 28 31 31
13.2 13.3 13.4 14 15	Bidirectional logic level-shifting application Power-up considerations Enable times Package outline Abbreviations Revision history	26 27 27 28 31 31 32
13.2 13.3 13.4 14 15 16	Bidirectional logic level-shifting application Power-up considerations Enable times Package outline Abbreviations. Revision history. Legal information.	26 27 27 28 31 31 32 32
13.2 13.3 13.4 14 15 16 17	Bidirectional logic level-shifting application Power-up considerations Enable times Package outline Abbreviations. Revision history. Legal information. Data sheet status	26 27 28 31 31 32 32 32
13.2 13.3 13.4 14 15 16 17 17.1	Bidirectional logic level-shifting application Power-up considerations Enable times. Package outline. Abbreviations. Revision history. Legal information. Data sheet status Definitions.	26 27 27 28 31 31 32 32 32
13.2 13.3 13.4 14 15 16 17 17.1 17.2 17.3	Bidirectional logic level-shifting application Power-up considerations	26 27 27 28 31 31 32 32 32 32 32



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